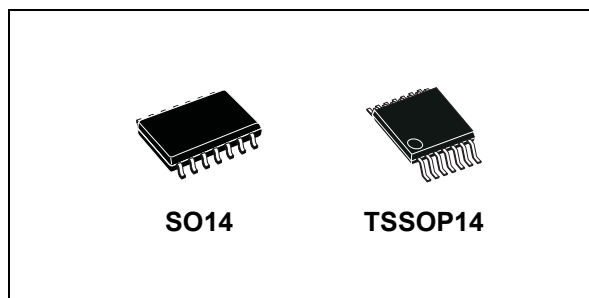


Quad bus buffer (3-state)

Datasheet - production data



- Balanced propagation delays:
 $t_{PLH} \equiv t_{PHL}$
- Wide operating voltage range:
 $V_{CC} (opr) = 2\text{ V to }6\text{ V}$
- Pin and function compatible with 74 series 126
- ESD performance
 - CDM: 1 kV
 - HBM: 2 kV
 - MM: 200 V

Features

- High-speed:
 $t_{PD} = 8\text{ ns (typ.) at }V_{CC} = 6\text{ V}$
- Low power dissipation:
 $I_{CC} = 4\text{ }\mu\text{A (max.) at }T_A = 25\text{ }^\circ\text{C}$
- High noise immunity:
 $V_{NIH} = V_{NIL} = 28\% V_{CC} (\text{min})$
- Symmetrical output impedance:
 $I_{OH} = I_{OL} = 6\text{ mA (min.)}$

Description

The M74HC126 is a high-speed CMOS quad buffer (3-state) fabricated with silicon gate C²MOS technology.

The device requires the 3-state control input, G, to be set high to place the output into high impedance state.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

Table 1. Device summary

Order code	Temp. range	Package	Packaging	Marking
M74HC126RM13TR	-55 °C to 125 °C	S014	Tape and reel	74HC126
M74HC126YRM13TR ⁽¹⁾	-40 °C to 125 °C	SO14 (automotive grade)		74HC126Y
M74HC126TTTR	-55 °C to 125 °C	TSSOP14		HC126
M74HC126YTTTR ⁽¹⁾	-40 °C to 125 °C	TSSOP14 (automotive grade)		HC126Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

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1 Pin information

Figure 1. Pin connection and IED logic symbols

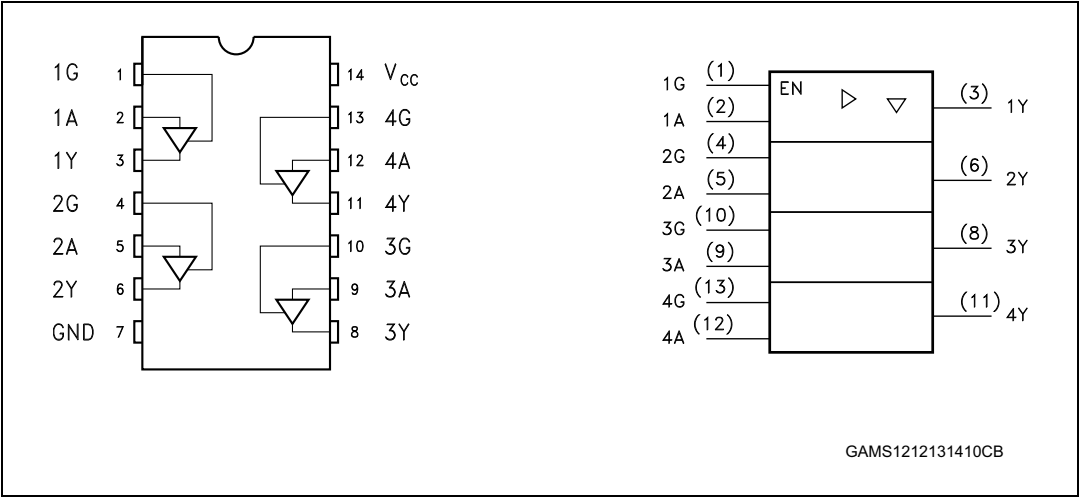


Table 2. Pin description

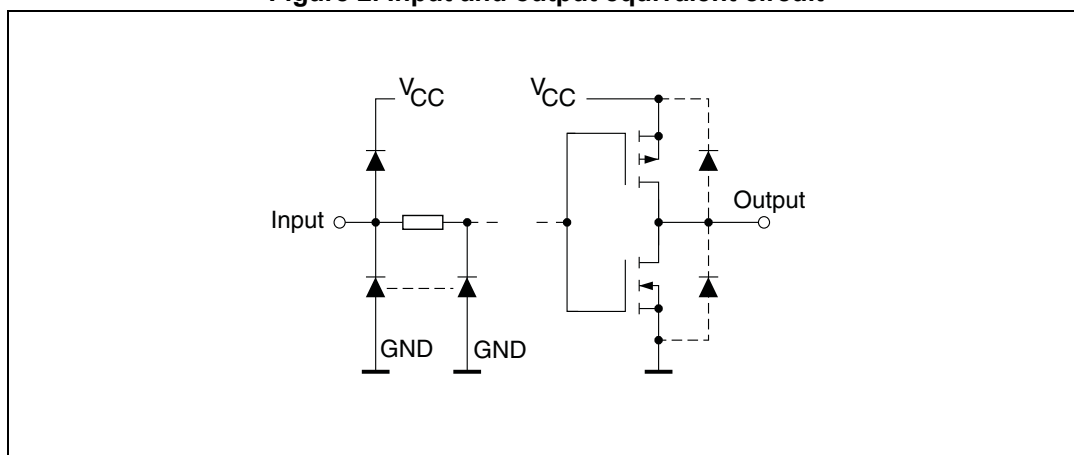
Pin no	Symbol	Name and function
1, 4, 10, 13	1G to 4G	Output enable input
2, 5, 9, 12	1A to 4A	Data inputs
3, 6, 8, 11	1Y to 4Y	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

2 Functional description

Table 3. Truth table

A	G	Y
X	L	Z
L	H	L
H	H	H

Figure 2. Input and output equivalent circuit



3 Electrical characteristics

“Absolute maximum ratings” are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

Table 4. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to +7	V
V _I	DC input voltage	-0.5 to V _{CC} + 0.5	
V _O	DC output voltage		
I _{IK}	DC input diode current	±20	mA
I _{OK}	DC output diode current		
I _O	DC output current	±35	
I _{CC} or I _{GND}	DC V _{CC} or ground current	±70	
P _D	Power dissipation	500 ⁽¹⁾	mW
T _{stg}	Storage temperature	-65 to +150	°C
T _L	Lead temperature (10 sec)	300	

1. 500 mW at 65 °C; derate to 300 mW by 10 mW/°C from 65 °C to 85 °C

Table 5. Recommended operating conditions

Symbol	Parameter		Value	Unit
V _{CC}	Supply voltage		2 to 6	V
V _I	Input voltage		0 to V _{CC}	
V _O	Output voltage			
T _{op}	Operating temperature		-55 to 125	°C
t _r t _f	Input rise and fall time	V _{CC} = 2.0 V	0 to 1000	ns
		V _{CC} = 4.5V	0 to 500	
		V _{CC} = 6.0 V	0 to 400	

Table 6. DC specifications

Symbol	Parameter	Test condition		Value							Unit	
		V _{CC} (V)		T _A = 25 °C			-40 to 85 °C		-55 to 125 °C			
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
V _{IH}	High level input voltage	2.0		1.5			1.5		1.5		V	
		4.5		3.15			3.15		3.15			
		6.0		4.2			4.2		4.2			
V _{IL}	Low level input voltage	2.0				0.5		0.5		0.5	V	
		4.5				1.35		1.35		1.35		
		6.0				1.8		1.8		1.8		
V _{OH}	High level output voltage	2.0	I _O = -20 μA	1.9	2.0		1.9		1.9		V	
		4.5	I _O = -20 μA	4.4	4.5		4.4		4.4			
		6.0	I _O = -20 μA	5.9	6.0		5.9		5.9			
		4.5	I _O = -6.0 mA	4.18	4.31		4.13		4.10			
		6.0	I _O = -7.8 mA	5.68	5.8		5.63		5.60			
V _{OL}	Low level output voltage	2.0	I _O = 20 μA		0.0	0.1		0.1		0.1	V	
		4.5	I _O = 20 μA		0.0	0.1		0.1		0.1		
		6.0	I _O = 20 μA		0.0	0.1		0.1		0.1		
		4.5	I _O = 6.0 mA		0.17	0.26		0.33		0.40		
		6.0	I _O = 7.8 mA		0.18	0.26		0.33		0.40		
I _I	Input leakage current	6.0	V _I = V _{CC} or GND			±0.1		±1		±1	μA	
I _{OZ}	High impedance output leakage current	6.0	V _I = V _{IH} or V _{IL} V _O = V _{CC} or GND			±0.5		±5		±10	μA	
I _{CC}	Quiescent supply current	6.0	V _I = V _{CC} or GND			4		40		80	μA	

Table 7. AC electrical characteristics
(Input $t_r = t_f = 6$ ns)

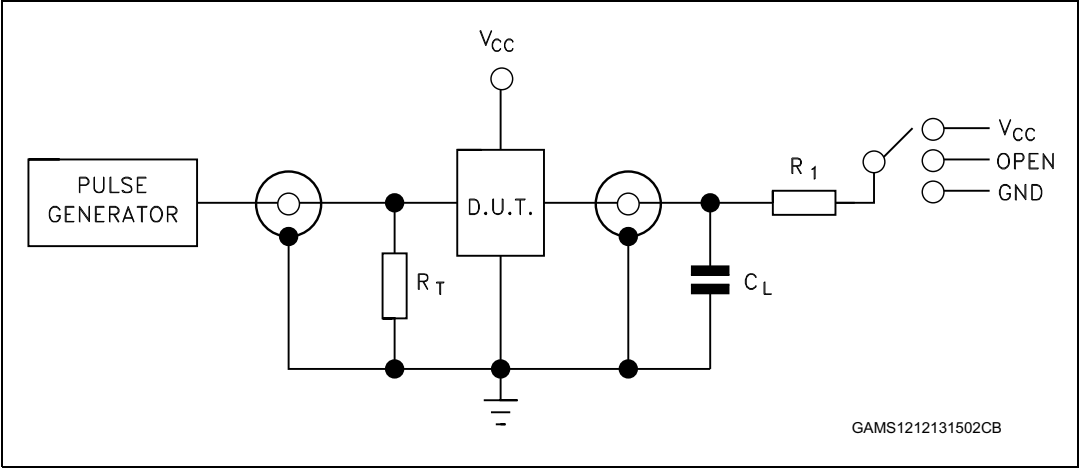
Symbol	Parameter	Test condition			Value								Unit
		V _{CC} (V)	C _L (pF)		T _A = 25 °C			-40 to 85 °C		-55 to 125 °C			
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
t _{TLH} , t _{THL}	Output transition time	2.0	50			20	60		75		90	ns	
		4.5		6		12	15		18				
		6.0		5		10	13		15				
t _{PLH} , t _{PHL}	Propagation delay time	2.0	50			36	75		95		110	ns	
		4.5		9		15	19		22				
		6.0		8		13	16		19				
		2.0	150			52	105		130		160	ns	
		4.5		13		21	26		32				
		6.0		11		18	22		27				
t _{PZL} , t _{PZH}	High impedance output enable time	2.0	50	R _L = 1 kΩ		36	75		95		110	ns	
		4.5				9	15		19		22		
		6.0				8	13		16		19		
		2.0	150			52	105		130		160	ns	
		4.5				13	21		26		32		
		6.0				11	18		22		27		
t _{PLZ} , t _{PHZ}	High impedance output disable time	2.0	50	R _L = 1 kΩ		48	80		100		120	ns	
		4.5				12	16		20		24		
		6.0				10	14		17		20		

Table 8. Capacitive characteristics

Sym	Parameter	Test condition	Value							Unit
		V _{CC} (V)	T _A = 25 °C			-40 to 85 °C		-55 to 125 °C		
			Min	Typ	Max	Min	Max	Min	Max	
C _{IN}	Input capacitance	5.0	-	5	10	-	10	-	10	pF
C _{PD}	Power dissipation capacitance ⁽¹⁾			35						

1. C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load (refer to test circuit). Average operating current can be obtained by the following equation:
 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per buffer).

Figure 3. Test circuit



1. Legend:
 C_L = 50 pF/150 pF or equivalent (includes jig and probe capacitance).
 R_1 = 1 k Ω or equivalent.
 R_T = Z_{OUT} of pulse generator (typically 50 Ω).

Table 9. Propagation delay time configuration

Test	Switch
t_{PLH} , t_{PHL}	Open
t_{PZL} , t_{PLZ}	V_{CC}
t_{PZH} , t_{PHZ}	GND

Figure 4. Waveform 1: propagation delay times
(f = 1 MHz; 50 % duty cycle)

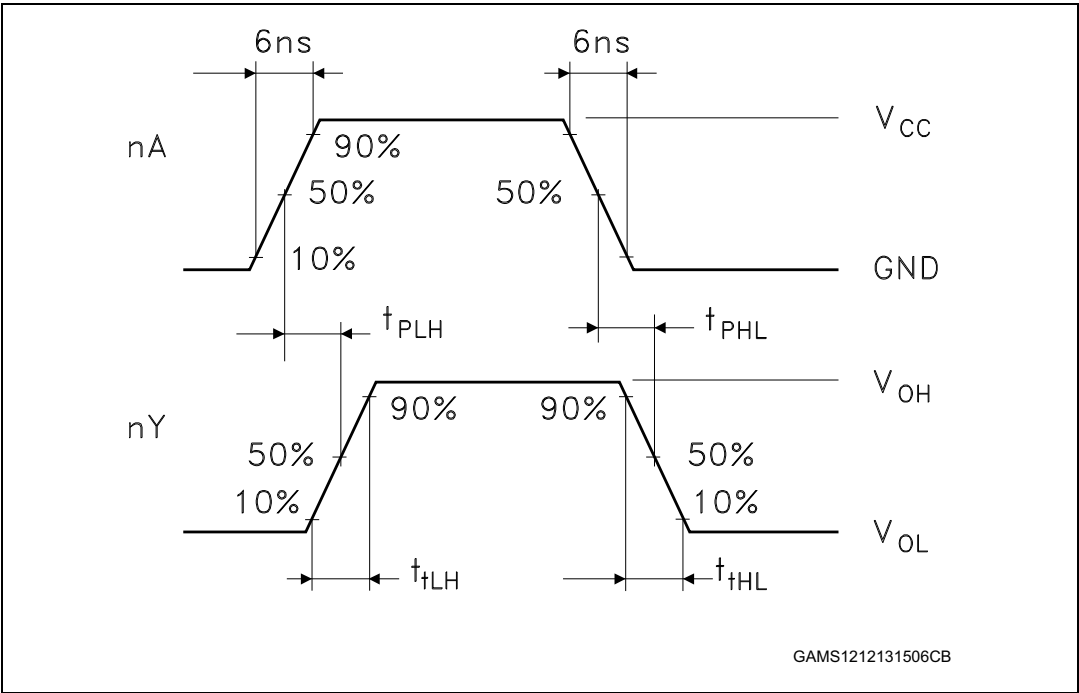
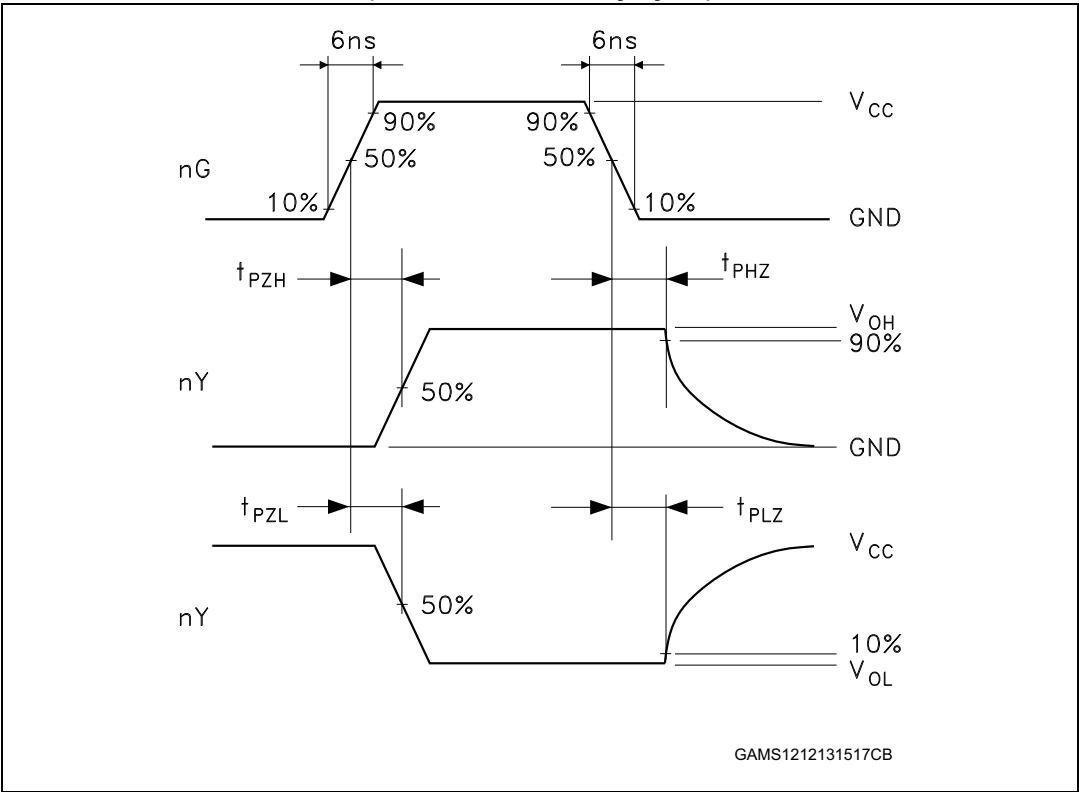


Figure 5. Waveform 2: Output enable and disable times
(f = 1 MHz; 50 % duty cycle)



4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

4.1 SO14 package information

Figure 6. SO14 package mechanical drawing

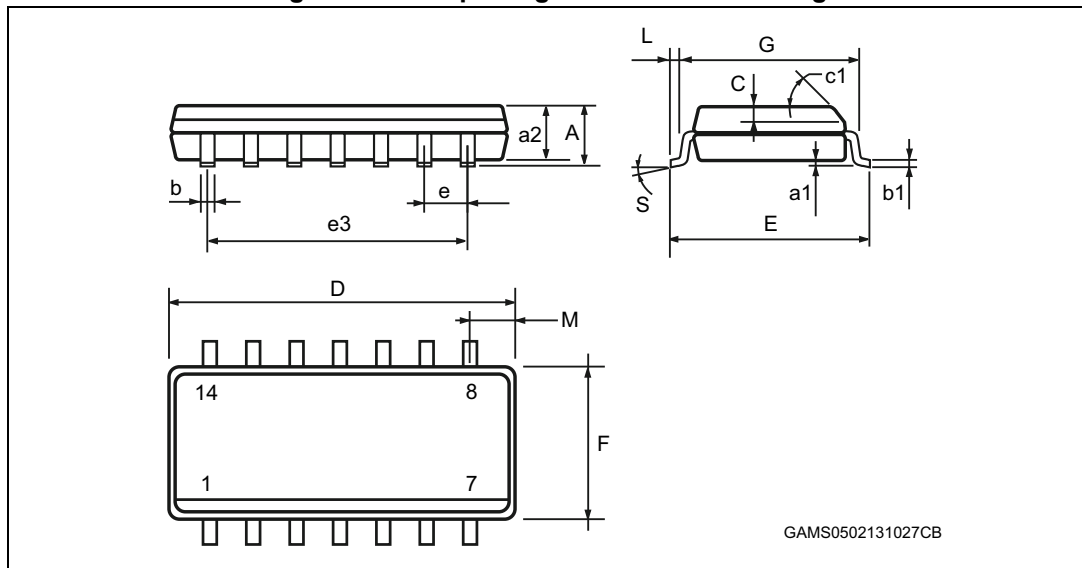


Table 10. SO14 package mechanical data

Ref	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1		45 °			45 °	
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S			8 °			8 °

4.2 TSSOP14 package information

Figure 7. TSSOP14 package mechanical drawing

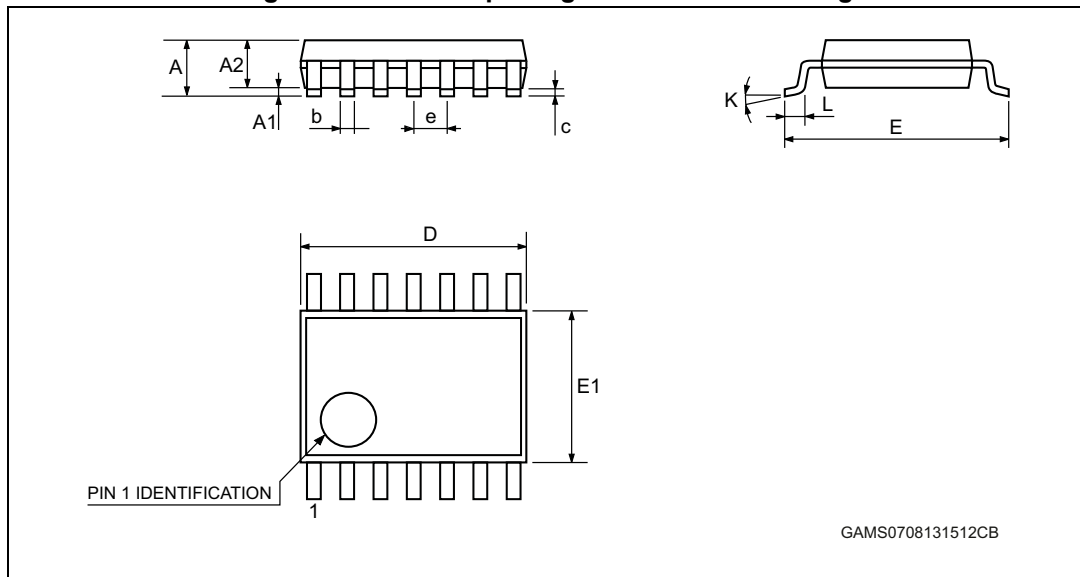


Table 11. TSSOP14 package mechanical data

Ref	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65			0.0256	
K	0 °		8 °	0 °		8 °
L	0.45	0.60	0.75	0.018	0.024	0.030

5 Ordering information

Table 12. Order codes

Order code	Temp. range	Package	Packaging	Marking
M74HC126RM13TR	-55 °C to 125 °C	S014	Tape and reel	74HC126
M74HC126YRM13TR ⁽¹⁾	-40 °C to 125 °C	SO14 (automotive grade)		74HC126Y
M74HC126TTR	-55 °C to 125 °C	TSSOP14		HC126
M74HC126YTTR ⁽¹⁾	-40 °C to 125 °C	TSSOP14 (automotive grade)		HC126Y

1. Qualification and characterization according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 and Q002 or equivalent.

6 Revision history

Table 13. Document revision history

Date	Revision	Changes
Aug-2001	1	Initial release.
13-Dec-2013	3	Removed DIP14 package Features : added ESD information Table 1: Device summary : updated order codes, added automotive grade order codes, added temperature range and marking details. Added Section 5: Ordering information .

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